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APPLICATION FOR
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SPECIFICATION

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Title of the Invention: OSCILLATOR CIRCUIT

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DESCRIPTION

OSCILLATOR CIRCUIT

5 **Technical Field**

The present invention relates to an oscillator circuit used for a radio transmitter and a radio receiver, et cetera.

10 **Background Art**

In an AM and an FM receivers, a local oscillator circuit generates a signal having a certain frequency difference from a received signal and converts the received signal into a specified intermediate frequency signal by mixing the received signal with the local oscillation signal.

In making an AM or FM receiver circuit by an integrated circuit ("IC" hereinafter), a local oscillator circuit has been separately mounted onto a printed circuit board having an IC for the receiver mounted thereon, because capacitances and inductance values for gaining a signal having a required oscillation frequency are too large for forming the capacitors and inductances within the IC.

25 This has required externally mounted components

for a receiver or transmitter IC, causing a problem of higher component and assembly costs. Furthermore, there has also been a problem of an increased size of the printed circuit board in need of space for mounting capacitors and coils thereon.

Disclosure of Invention

The challenge of the present invention is to eliminate externally mounted components for an oscillator circuit mounted on a semiconductor integrated circuit.

An oscillator circuit according to the present invention comprises an oscillating unit comprising an inductance and a variable capacitance element and generating a signal having a frequency of n times a target frequency; and a divider circuit dividing a signal generated by the oscillating unit into $1/n$ frequency, wherein the oscillating unit comprising an inductance and a variable capacitance element, and the divider circuit are formed on a semiconductor integrated circuit board.

Another oscillator circuit according to the present invention comprises an oscillating unit comprising an inductance and a variable capacitance element and generating a signal having a frequency of

n times a target frequency; a control voltage generation circuit generating a control voltage for controlling an oscillation frequency of the oscillating unit and outputting the control voltage to the oscillating unit; 5 and a divider circuit dividing a signal generated by the oscillating unit into $1/n$ frequency, wherein the oscillating unit comprising an inductance and a variable capacitance element, the control voltage generation circuit and the divider circuit are formed on a 10 semiconductor integrated circuit board.

According to the above described invention, components for an oscillator circuit including a variable capacitance element and an inductance can be formed on a semiconductor integrated circuit board. This 15 eliminates a need of externally mounting an inductance and a variable capacitance element for the oscillator circuit formed on a semiconductor integrated circuit board, reducing the component and assembly costs.

Furthermore, by forming the components of the 20 oscillator circuit on a semiconductor integrated circuit while eliminating the externally mounted components, the board mounting a semiconductor integrated circuit can be made more compact.

In the above described invention, the oscillating 25 unit comprises a plurality of MOSFETs, an inductance

and a variable capacitance element.

This configuration enables the inductance and the variable capacitance element to be formed on a semiconductor integrated circuit board.

5 In the above described invention, the oscillating unit comprises a plurality of MOSFET, an inductance and a variable capacitance element, and the control voltage generation circuit controls an oscillation frequency of the oscillating unit by outputting a control voltage
10 to the variable capacitance element for changing the capacitance thereof.

 This configuration enables the frequency of the oscillating unit to be controlled at n times a target frequency by changing the capacitance of variable
15 capacitance element through a control voltage outputted from the control voltage generation circuit.

 In the above described invention, the oscillating unit comprises a first and second MOSFETs, an inductance, a capacitor and a variable capacitance element; either
20 the source or drain of the first MOSFET is connected with the inductance and the capacitor, the gate of the first MOSFET is connected with either the source or drain of the second MOSFET, the gate of the second MOSFET is connected with either the source or drain of the first
25 MOSFET, and either the source or drain of the first MOSFET

is connected with the variable capacitance element by way of the capacitor.

This configuration enables oscillating unit comprising a first and second MOSFETs, an inductance, a capacitor and a variable capacitance element can be formed on a semiconductor integrated circuit board.

In the above described invention, the voltage generation circuit controls a oscillation frequency of the oscillating unit by outputting the control voltage to the variable capacitance element for changing the capacitance of the variable capacitance element.

This configuration enables the frequency of the oscillating unit to be set at n times a target frequency by changing the control voltage outputted from the control voltage generation circuit.

In the above described invention, the variable capacitance element is configured by a MOSFET.

This configuration enables a semiconductor integrated circuit board to build a variable capacitance element thereon.

In the above described invention, the control voltage generation circuit detects the phase difference between a divided signal of a signal generated by the oscillating unit and the reference signal, and outputs a control voltage according to the phase difference.

This comprisal enables the phase of a signal having frequency of n times a target frequency generated in the oscillating unit to be synchronous with that of a reference signal, thereby improving the accuracy of oscillation frequency generated in the oscillating unit up to that of the reference signal.

In the above described invention, the control voltage generation circuit is configured by a PLL synthesizer circuit comprising a programmable counter, a phase detection circuit comparing phases between a signal outputted from the programmable counter and the reference signal, and a low-pass filter blocking a high frequency component of an output signal of the phase detection circuit and outputting a DC control voltage to the oscillating unit.

This configuration improves the accuracy of oscillation frequency generated in the oscillating unit up to that of the reference signal. This also enables an oscillation frequency to be arbitrarily determined by changing data set in the programmable counter for instructing a division ratio.

In the above described invention, the divider circuit includes a divider circuit having a duty ratio of 50%.

This configuration enables the harmonics of $1/n$ -divided

signal in the divider circuit to be made up of the odd harmonics component only. This in turn allows the filter, equipped in the subsequent step to converting a received signal into an intermediate frequency signal by a signal having a $1/n$ frequency, to block the odd harmonics only, making the filter configuration simple and the area size thereof formed on a semiconductor integrated circuit smaller.

10 **Brief Description of Drawings**

Fig. 1 shows a circuit of an oscillating unit according to an embodiment;

Fig. 2 is a block diagram showing an oscillator circuit and a mixing circuit.

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Best Mode for Carrying Out the Invention

The embodiment according to the present invention in reference to the accompanying drawing is described as follows. Fig. 1 shows a circuitry of an oscillating unit of an IC used for an AM and an FM receivers according to the embodiment of the present invention. The IC used for an AM and an FM receivers is manufactured in a CMOS process.

As shown in Fig. 1, a gate G of each of two P-channel MOSFETs (i.e., MOS transistor) 12 and 13 are connected

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with drain D of each other, and each source S is commonly connected with a constant current source 14. The other terminal of the constant current source 14 is connected with a power source V_d .

5 The drain D of the MOSFET 12 is connected with an inductance (an inductor, a coil) L1 and a capacitor C1, the other terminal of the inductance L1 is grounded, and the other terminal of the capacitor C1 is connected with a voltage controlled variable capacitance element
10 (i.e., variable capacitance element) comprising a MOSFET 15. A varactor diode can be used for the variable capacitance element. The inductance L1 can be formed by a spiral, polygonal printed circuit pattern on a MOS IC board for example.

15 The drain D of the MOSFET 13 is grounded, while the gate G thereof is connected with the drain D of MOSFET 12 (at the connection point with the inductance L1).

 The drain D of the MOSFET 12 is connected with the capacitor C1 whose other terminal is connected with the
20 gate G of an N-channel MOSFET 15.

 A control voltage V_t by way of a resistor R1 is applied to the gate G of the MOSFET 15 whose drain D and source S are both grounded.

 The MOSFET 15 in this case functions as voltage

controlled variable capacitance element, with the capacitance between the gate G and source S (and the drain D) thereof being varied by changing the control voltage V_t .

5 An oscillating unit 11 is configured by an inductance-capacitance ("LC" hereinafter) oscillator circuit comprising the above described MOSFET 12 and 13, inductance L1, capacitor C1 and MOSFET 15.

10 For example, selecting an oscillation frequency of the oscillating unit 11 at 100 times a target frequency, or at 1 GHz, sets both the capacitance of the variable capacitance element comprising the capacitor C1 and the MOSFET 15, and the value of the inductance L1, all of which constitute the oscillating unit 11, at small values,
15 thereby enabling these elements to be formed on a MOS IC board.

 This in turn enables a MOS IC board to form the capacitor C1, the variable capacitance element (i.e., MOSFET 15) and the inductance L1 thereon for the LC
20 oscillator circuit, thus eliminating the externally mounted capacitors (including a variable capacitance element) and a coil (i.e., an inductance).

 The drain D of the MOSFET 12 is connected with the capacitor C2 whose other terminal is connected with the

non-inverting input terminal of an operational amplifier 16 of which the inverting input terminal is grounded.

Operations of such configured oscillating unit 11 are then described as follows. Let the MOSFET 12 be in
5 conduction, then the current goes through the source and drain of the MOSFET 12, the inductance L1 and to the capacitor C1. At this time, since the gate of the MOSFET 13 is applied by a drain voltage of the MOSFET 12 and the MOSFET 13 is turned off, the drain voltage
10 of the MOSFET 12 goes through the gate G and drain D of the MOSFET 13, and returns to the source of the MOSFET 12, thereby oscillating the circuit. The oscillation frequency of the LC oscillator circuit is variable by the control voltage V_t applied to the gate of the MOSFET
15 15.

Now, Fig. 2 is a block diagram showing an oscillator circuit comprising the oscillating unit 11, a PLL synthesizer (i.e., control voltage generation circuit) 21 and a divider circuit 22, as well a mixing circuit
20 23.

The PLL synthesizer 21 comprises a programmable counter 24, a phase detector 25 and a low-pass filter (LPF) 26.

The programmable counter 24 divides a signal having

a frequency of n times f (1 GHz for example), where f is a target frequency inputted from the oscillating unit 11, in accordance with a division ratio specification data inputted into the data input terminal thereon and
5 outputs it to the phase detector 25. The programmable counter 24 can arbitrarily change the division ratio by the externally programmable division ratio specification data. Changing the division ratio can arbitrarily change the frequency of the oscillating unit
10 11.

The frequency, $n * f$, where f is the target frequency, can only be such that the required values of the inductance and capacitors are formed on an IC board. A preferred frequency, $n * f$, is 700 MHz or higher. In the present
15 embodiment, when the target frequency is set at 10 MHz, the frequency, $n * f$, is established at 1 GHz so as to form the inductance and capacitors on an IC board, with n being established at 100.

The phase detector 25 detects the phase difference
20 between a signal divided by the programmable counter 24 and a reference signal.

The low-pass filter (LPF) 26 blocks a high frequency component (i.e., signal having higher frequencies than a cut-off frequency) of a signal according to the phase

difference outputted from the phase detector 25 and outputs a DC control voltage V_t to the oscillating unit 11.

That is, the PLL synthesizer 21 compares between
5 the phase of a signal generated in the oscillating unit 11 divided by a specified division ratio and that of the reference signal, generates a DC control voltage according to the phase difference, and control the oscillation frequency of the oscillating unit 11 by using
10 the control voltage V_t . This controls the oscillation frequency of the oscillating unit 11 at $n \cdot f$, i.e., n times the target frequency f . Meanwhile, the PLL synthesizer 21 synchronizes the phase of a divided signal by the programmable counter 24 with that of the reference
15 signal, thus enabling the accuracy of an oscillation signal frequency to be improved up to that of the reference signal.

A divider circuit 22 comprises a $1/k$ divider circuit 27 dividing a signal having the frequency of $n \cdot f$, i.e.,
20 n times the target frequency f , outputted from the oscillating unit 11 into $1/k$ frequency and a $1/2$ divider circuit 28 further bisecting the output signal from the $1/k$ divider circuit 27. The $1/2$ divider circuit 28 outputs two signals, f_1 and f_2 , having an equal frequency

and different phases by 180° from each other. Note that a $1/k$ divider circuit can be configured by a combination of a $1/2$ divider circuit, $1/3$ divider circuit, et cetera.

5 A signal having the frequency of $n*f$, i.e., n times the target frequency f , generated by the oscillating unit 11 is divided into $1/n$ frequency, i.e., a signal having the target frequency f by the divider circuit 22 and the resultant signal is outputted to a mixing circuit 23.

10 The mixing circuit 23 mixes a signal received through an antenna unit 29, synchronized and amplified by a high frequency amplification circuit 30 with the local oscillation signals, f_1 and f_2 , having an equal frequency and different phases by 180° from each other
15 outputted from the divider circuit 22, and thereby converts into an intermediate frequency signal.

Operations of the local oscillator circuit configured as noted above are then described as follows. A signal having the frequency of $n*f$ (e.g., 1 GHz), i.e.,
20 n times a target frequency f (e.g., 10 MHz), generated by the oscillating unit 11 is divided by the programmable counter 24, the phase difference between the divided signal and the reference signal is detected by the phase detector 25, and a DC control voltage according to the

phase difference is outputted from the low-pass filter 26.

The control voltage V_t is applied to the gate of the MOSFET 15 equipped in the oscillating unit 11 as shown by Fig. 1, the capacitance between the gate and source (and drain) of the MOSFET 15 changes in response to the control voltage V_t . This changes an oscillation frequency of the oscillating unit 11 comprising the capacitor C_1 , the inter-electrode capacitance of the MOSFET 15, the inductance L_1 , and the MOSFET 12 and 13, thereby controlling the oscillation frequency at $n \cdot f$, i.e., n times the target frequency f .

The divider circuit 22 divides a signal outputted from the oscillating unit 11 into $1/k$ frequency and further bisects it. The overall division ratio in the divider circuit 22 is designed for $1/n$, thereby dividing a signal having the frequency of $n \cdot f$, i.e., n times the target frequency f , generated by the oscillating unit 11 into $1/n$ frequency and thus converting to the target frequency, f .

Meanwhile, since the duty ratio of the $1/2$ divider circuit 28 is set at 50%, the odd harmonics in the fundamental harmonics is only generated, not the even harmonics. Therefore, the design of a filter for

removing the harmonics off the intermediate frequency signal is so as to remove the odd harmonics only, making the filter configuration simple. This in turn makes the area size of the filter formed on a MOS IC board small.

5 According to the present embodiment, the inductance and capacitance (including a variable capacitance element) of an oscillator circuit can be established at small values by setting the frequency of the oscillator circuit at n times the target frequency.
10 This then enables the inductance and the variable capacitance elements to be formed on a MOS IC board, eliminating a need to mount the inductance and the variable capacitance elements outside of the IC (i.e., on a printed circuit board on which the IC is mounted).
15 This in turn reduces component and assembly costs of an AM and an FM receivers.

 Note here that such an oscillator circuit can be configured not only by an inductance, capacitors, a variable capacitance element and MOSFETs, but also by
20 an inductance, a variable capacitance element and MOSFETs.

 The present invention is not limited by the above described embodiment, but may be configured as follows:

(1) A circuit of the oscillating unit 11 is not

only applicable to the oscillator circuit described in the embodiment, but also to any oscillator circuits using an inductance and a capacitor;

5 (2) An oscillation frequency of the oscillator circuit is not only controlled by the voltage applied to a voltage controlled variable capacitance element, but also by the current control or changing the impedance, except for the capacitance.

10 (3) A circuit for controlling a frequency of the oscillating unit is not limited to a PLL synthesizer 21, but can be any circuits so long as controlling to set the frequency at n times a target frequency.

15 (4) The present invention is not only applicable to a MOS IC, but also to a bipolar transistor IC or an IC having both bipolar and MOS transistors.

20 (5) The present invention is not only applicable to a single purpose IC for an AM and an FM receivers, but also to an oscillator circuit of any IC for radio communications which will be equipped in other apparatuses such as a personal computer.

According to the present invention, the inductance and the variable capacitance element of an oscillator circuit can be formed on a semiconductor IC board, thus eliminating externally mounted components, and thereby

reducing the component and assembly costs. And by eliminating the externally mounted components in an oscillator circuit, it is further possible to configure a printed circuit board mounting a semiconductor IC more compact.